STPS2150



Power Schottky rectifier

Main product characteristics

I _{F(AV)}	2 A
V _{RRM}	150 V
T _j (max)	175° C
V _F (max)	0.67 V

Description

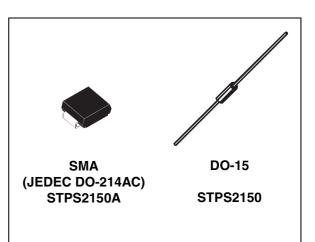
150 V Power Schottky rectifier are suited for switch mode power supplies on up to 24 V rails and high frequency converters.

Packaged in SMA and Axial, this device is intended for use in consumer and computer applications like TV, STB, PC and DVD where low drop forward voltage is required to reduce power dissipation.

Order Codes

Part Number	Marking
STPS2150A	2150
STPS2150	STPS2150
STPS2150RL	STPS2150

Table 1. Absolute Ratings (limiting values)



Features and benefits

- Negligible switching losses
- Low forward voltage drop for higher efficiency and extented battery life
- Low thermal resistance
- Surface mount miniature package
- Avalanche capability specified

	Value	Unit			
Repetitive peak reverse voltage			150	V	
RMS forward voltage			15	А	
(AV) Average forward current		$T_L = 145^\circ C \delta = 0.5$	2	А	
Average forward current	DO-15	$T_L = 130^\circ C$ $\delta = 0.5$	2		
Surge non repetitive forward SMA		t – 10 ms sinusoidal	75	A	
I _{FSM} current	DO-15	$t_p = 10 \text{ ms sinusoidal}$	150	A	
Repetitive peak avalanche power $tp = 1 \ \mu s$ $Tj = 25^{\circ} C$			2400	W	
Storage temperature range			-65 to + 175	°C	
Maximum operating junction temperature ⁽¹⁾			175	°C	
	RMS forward voltage Average forward current Surge non repetitive forward current Repetitive peak avalanche powe Storage temperature range	Repetitive peak reverse voltage RMS forward voltage Average forward current SMA DO-15 Surge non repetitive forward current SMA current DO-15 Repetitive peak avalanche power Storage temperature range	$\begin{array}{c} \mbox{RMS forward voltage} \\ \mbox{Average forward current} & \begin{tabular}{c} SMA & T_L = 145^\circ C & \delta = 0.5 \\ \hline DO-15 & T_L = 130^\circ C & \delta = 0.5 \\ \hline DO-15 & T_L = 130^\circ C & \delta = 0.5 \\ \hline Surge non repetitive forward \\ \hline current & \end{tabular} \\ \hline DO-15 & t_p = 10 \mbox{ ms sinusoidal} \\ \hline Repetitive peak avalanche power & tp = 1 \mu s \ Tj = 25^\circ C \\ \hline Storage temperature range & \end{tabular}$	Repetitive peak reverse voltage150RMS forward voltage15Average forward current SMA $T_L = 145^{\circ}$ C $\delta = 0.5$ 2Surge non repetitive forward current SMA $T_L = 130^{\circ}$ C $\delta = 0.5$ 2Surge non repetitive forward current SMA $T_p = 10 \text{ ms sinusoidal}$ 75DO-15 $T_p = 10 \text{ ms sinusoidal}$ 150Repetitive peak avalanche power $tp = 1 \mu s Tj = 25^{\circ} C$ 2400Storage temperature range-65 to + 175	

1. $\frac{dPtot}{dTj} > \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

1 Characteristics

Table 2.Thermal resistance

Symbol	Parameter				Unit
Б	Junction to lead		SMA	20	° C/W
R _{th(j-l)}	JUNCTION TO TEAU	Lead length = 10 mm	DO-15	30	C/VV

Table 3. Static electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур	Max.	Unit
I_ (1)	I _R ⁽¹⁾ Reverse leakage current	$T_j = 25^\circ C$	VV		0.5	1.5	μA
'R `´		T _j = 125° C	$V_{R} = V_{RRM}$		0.5	1.5	mA
	V _F ⁽²⁾ Forward voltage drop	$T_j = 25^\circ C$	I _F = 2 A		0.78	0.82	
V (2)		T _j = 125° C			0.62	0.67	V
VF		T _j = 25° C	1 - 4 4		0.86	0.89	v
		T _j = 125° C	I _F = 4 A		0.70	0.75	

1. $t_p = 5 \text{ ms}, \delta < 2\%$

2. $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation: P = 0.59 x $I_{F(AV)}$ + 0.04 $I_{F}^{2}(RMS)$

Figure 1. Average forward power dissipation versus average forward current

Figure 2. Average forward current versus ambient temperature (δ = 0.5)

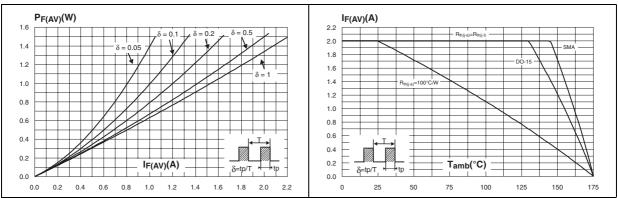
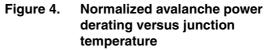
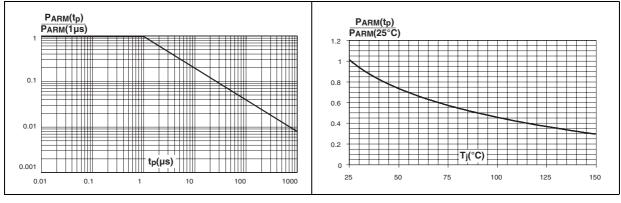




Figure 3. Normalized avalanche power derating versus pulse duration





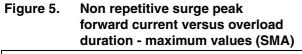


Figure 6. Non repetitive surge peak forward current versus overload duration - maximum values (DO-15)

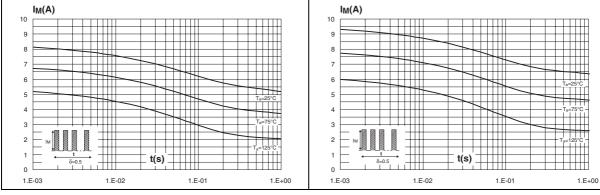
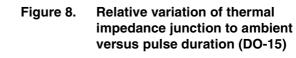
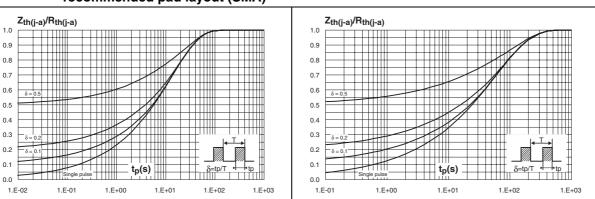


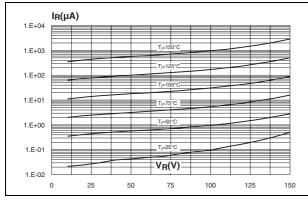
Figure 7. Relative variation of thermal impedance junction to ambient versus pulse duration - epoxy printed circuit board, $e_{Cu} = 35 \ \mu m$, recommended pad layout (SMA)

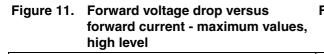


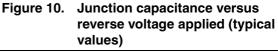


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Figure 9. Reverse leakage current versus reverse voltage applied (typical values)







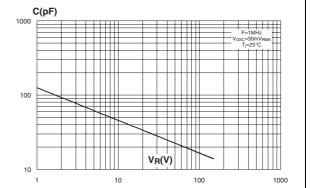


Figure 12. Forward voltage drop versus forward current - maximum values, low level

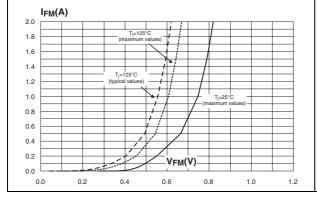


Figure 13. Thermal resistance junction to ambient versus copper surface under each lead - Epoxy printed circuit board FR4, $e_{Cu} = 35 \ \mu m$ (SMA)

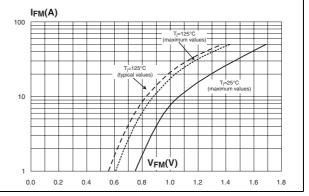
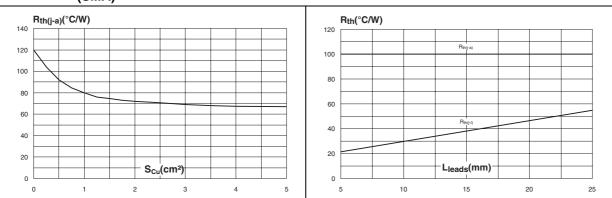


Figure 14. Thermal resistance versus lead length (DO-15)





2 Package information

Band shows cathode. Epoxy meets UL94, V0.

Table 4. SMA Package dimensions

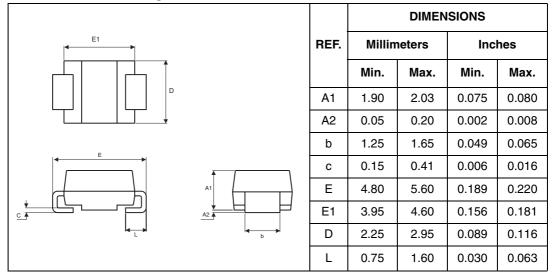


Figure 15. SMA Foot Print Dimensions (in mm)

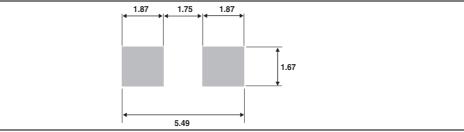


Table 5. DO-15 Package dimensions

		DIMENSIONS			
	REF.	Millim	neters	Inc	hes
		Min.	Max.	Min.	Max.
↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓	Α	6.05	6.75	0.238	0.266
	В	2.95	3.53	0.116	0.139
	С	26	31	1.024	1.220
	D	0.71	0.88	0.028	0.035

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS2150A	2150	SMA	0.068 g	5000	Tape and reel
STPS2150	STPS2150	DO-15	0.4 g	2000	Ammopack
STPS2150RL	STPS2150	DO-15	0.4 g	5000	Tape and reel

4 Revision history

Date	Revision	Description of Changes
Jul-2003	ЗA	Last update.
Aug-2004	4	SMA package dimensions update. Reference A1 max. changed from 2.70mm (0.106inc.) to 2.03mm (0.080).
31-May-2006	5	Reformatted to current standard. Added ECOPACK statement. Updated SMA footprint in Figure 15. Changed nF to pF in Figure 10.



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